

Publications about samples irradiated at the Karlsruhe Irradiation Facility

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1. Casse, G.-L., Affolder, A., Allport, P. P. & Wormald, M. Measurements of charge collection efficiency with microstrip detectors made on various substrates after irradiations with neutrons and protons with different energies. *Proceedings of Science VERTEX2008*, 036 (2008).
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- Physics Research Section A: Accelerators, Spectrometers, Detectors and Associated Equipment* **658**, 11–16 (2011).
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